

# 74HC4316; 74HCT4316

Quad single-pole single-throw analog switch

Rev. 3 — 2 January 2017

Product data sheet

## 1. General description

The 74HC4316; 74HCT4316 is a quad single pole, single throw analog switch (SPST). Each switch features two input/output terminals (nY and nZ) and an active HIGH enable input (nS). When nS is LOW, the analog switch is turned off. When  $\bar{E}$  is HIGH all four analog switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

## 2. Features and benefits

- Input levels  $\bar{E}$  and nS inputs:
  - ◆ For 74HC4316: CMOS level
  - ◆ For 74HCT4316: TTL level
- Low ON resistance:
  - ◆ 160  $\Omega$  (typical) at  $V_{CC} - V_{EE} = 4.5$  V
  - ◆ 120  $\Omega$  (typical) at  $V_{CC} - V_{EE} = 6.0$  V
  - ◆ 80  $\Omega$  (typical) at  $V_{CC} - V_{EE} = 9.0$  V
- Logic level translation:
  - ◆ To enable 5 V logic to communicate with  $\pm 5$  V analog signals
- Typical break-before-make built in
- Specified in compliance with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from  $-40$  °C to  $+85$  °C and  $-40$  °C to  $+125$  °C

## 3. Applications

- Signal gating
- Modulation
- Demodulation
- Chopper

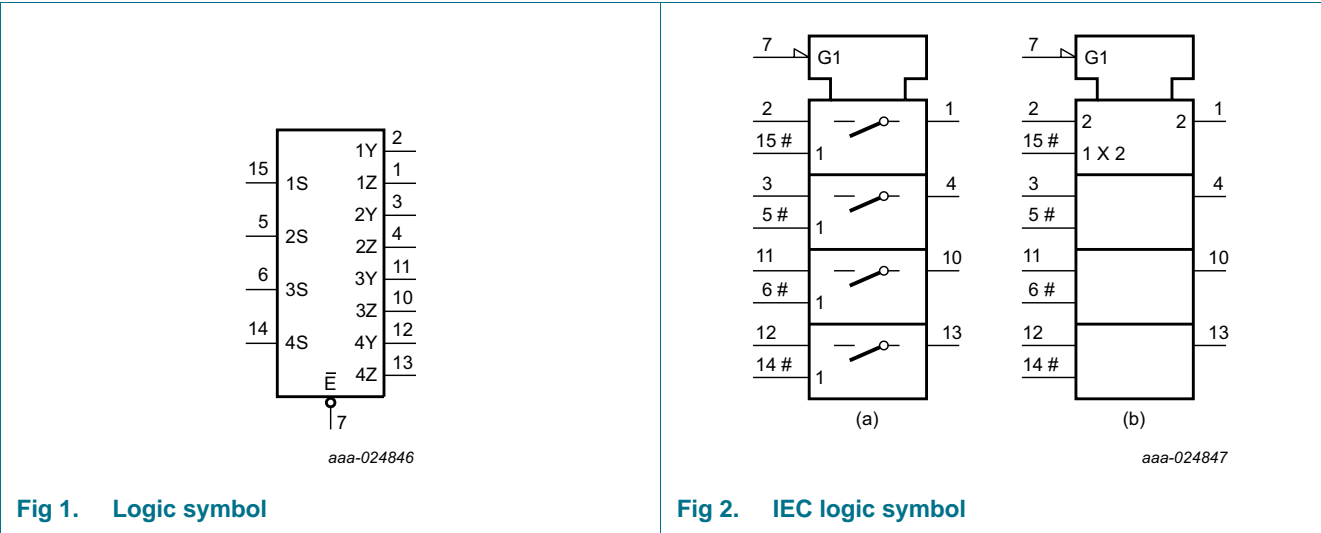


4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC4316D	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT4316D				
74HC4316DB	−40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HCT4316DB				
74HC4316PW	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HCT4316PW				

5. Functional diagram



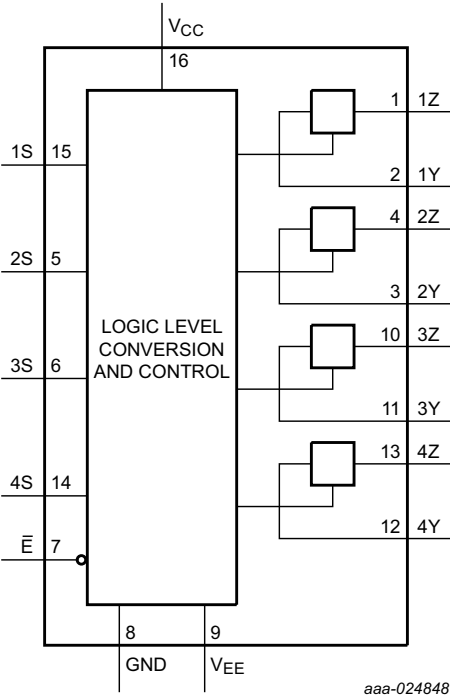


Fig 3. Functional diagram

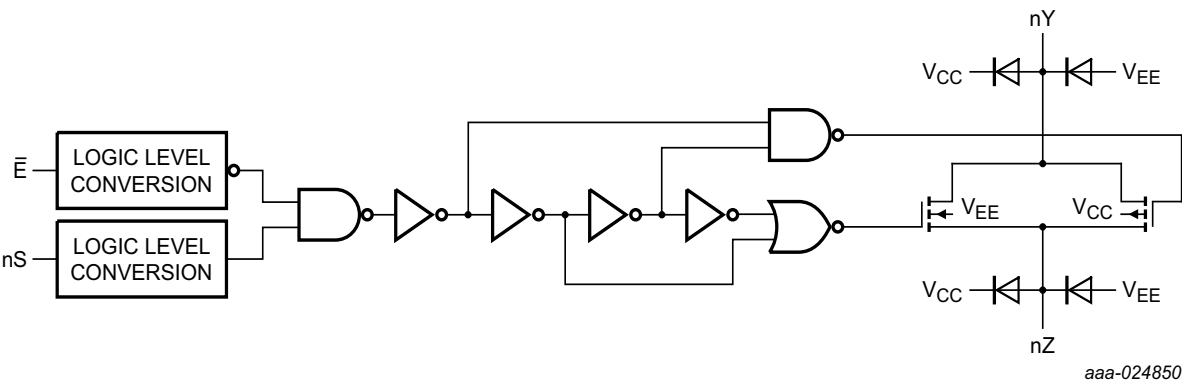
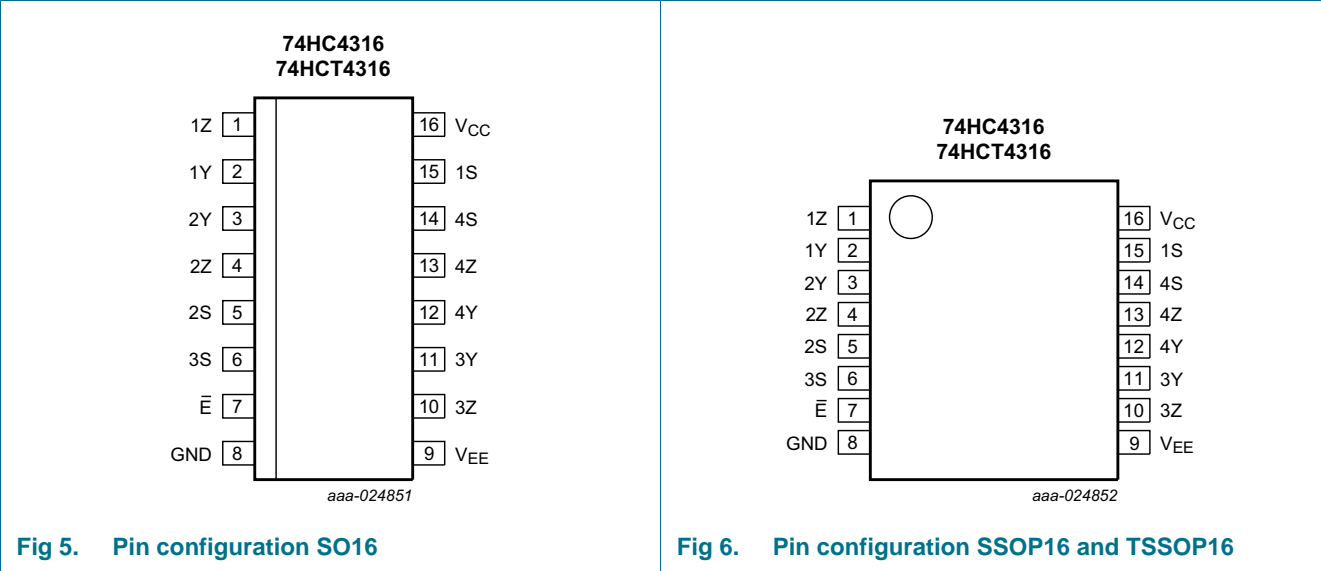


Fig 4. Schematic diagram (one switch)

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1Z, 2Z, 3Z, 4Z	1, 4, 10, 13	independent input or output
1Y, 2Y, 3Y, 4Y	2, 3, 11, 12	independent input or output
E̅	7	enable input (active LOW)
GND	8	ground (0 V)
V <sub>EE</sub>	9	negative supply voltage
1S, 2S, 3S, 4S	15, 5, 6, 14	select input (active HIGH)
V <sub>CC</sub>	14	positive supply voltage

7. Functional description

Table 3. Function table<sup>[1]</sup>

Input		Switch
E	nS	
L	L	OFF
L	H	ON
H	X	OFF

[1] H = HIGH voltage level;  
L = LOW voltage level;  
X = don't care.

## 8. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+11.0	V
$I_{IK}$	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	-	$\pm 20$	mA
$I_{SK}$	switch clamping current	$V_{SW} < -0.5\text{ V}$ or $V_{SW} > V_{CC} + 0.5\text{ V}$	-	$\pm 20$	mA
$I_{SW}$	switch current	$V_{SW} = -0.5\text{ V}$ to $V_{CC} + 0.5\text{ V}$ [1]	-	$\pm 25$	mA
$I_{EE}$	supply current		-	20	mA
$I_{CC}$	supply current		-	50	mA
$I_{GND}$	ground current		-50	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40\text{ °C}$ to $+125\text{ °C}$			
		SO16 and (T)SSOP16 packages [2]	-	500	mW
$P$	power dissipation	per switch	-	100	mW

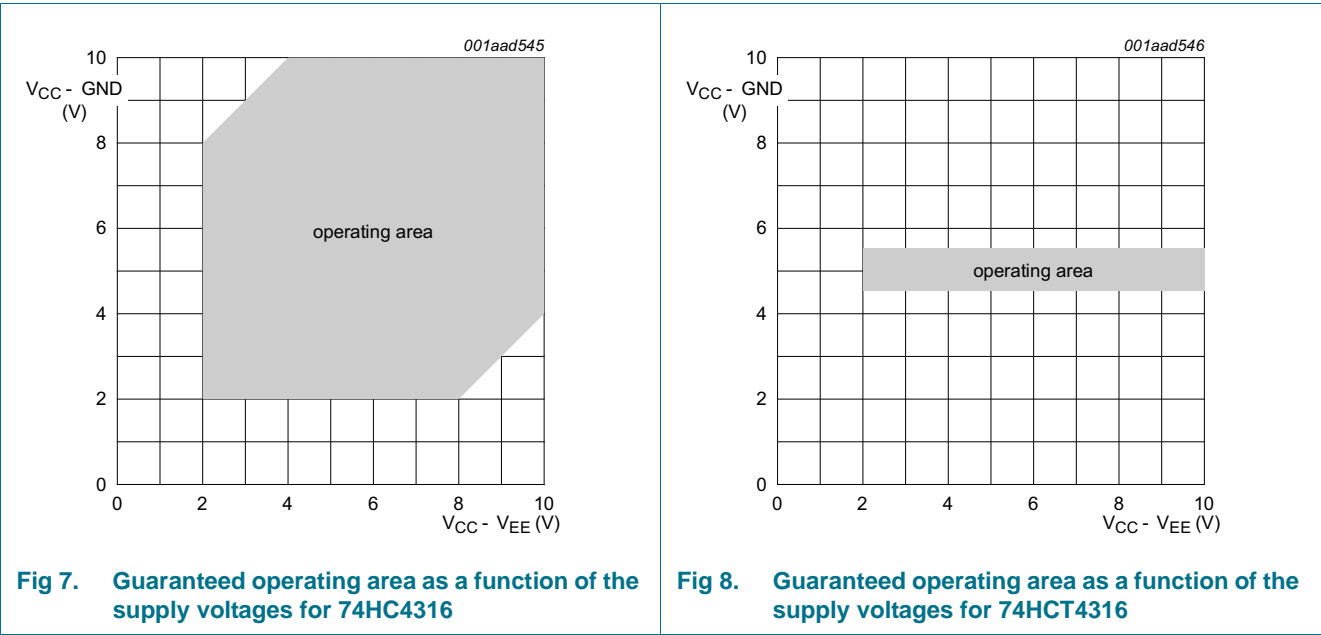
[1] To avoid drawing  $V_{CC}$  current out of terminal nZ, when switch current flows in terminals nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no  $V_{CC}$  current will flow out of terminals nY. In this case there is no limit for the voltage drop across the switch, but the voltages at nY and nZ may not exceed  $V_{CC}$  or  $V_{EE}$ .

[2] For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.  
For (T)SSOP16 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

## 9. Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Conditions	74HC4316			74HCT4316			Unit
			Min	Typ	Max	Min	Typ	Max	
$V_{CC}$	supply voltage	see <a href="#">Figure 7</a> and <a href="#">Figure 8</a>							
		$V_{CC} - GND$	2.0	5.0	10.0	4.5	5.0	5.5	V
		$V_{EE} - GND$	2.0	5.0	10.0	2.0	5.0	10.0	V
$V_I$	input voltage		GND	-	$V_{CC}$	GND	-	$V_{CC}$	V
$V_{SW}$	switch voltage		$V_{EE}$	-	$V_{CC}$	$V_{EE}$	-	$V_{CC}$	V
$T_{amb}$	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.0\text{ V}$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5\text{ V}$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0\text{ V}$	-	-	83	-	-	-	ns/V
		$V_{CC} = 10.0\text{ V}$	-	-	35	-	-	-	ns/V



10. Static characteristics

Table 6. RON resistance per switch for types 74HC4316 and 74HCT4316

$V_I = V_{IH}$  or  $V_{IL}$ ; for test circuit see [Figure 9](#).  
 $V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.  
 $V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.  
For 74HC4316:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .  
For 74HCT4316:  $V_{CC} - GND = 4.5\text{ V}$  and  $5.5\text{ V}$ ;  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

Symbol	Parameter	Conditions	25 °C		−40 °C to +85 °C		−40 °C to +125 °C		Unit
			Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	
RON(peak)	ON resistance (peak)	$V_{is} = V_{CC}$ to $V_{EE}$ <sup>[2]</sup>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 100\text{ }\mu\text{A}$	-	-	-	-	-	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	160	320	-	400	-	480	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	120	240	-	300	-	360	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	85	170	-	215	-	255	$\Omega$

**Table 6.**  $R_{ON}$  resistance per switch for types 74HC4316 and 74HCT4316 ...continued

$V_I = V_{IH}$  or  $V_{IL}$ ; for test circuit see [Figure 9](#).

$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

For 74HC4316:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

For 74HCT4316:  $V_{CC} - GND = 4.5\text{ V}$  and  $5.5\text{ V}$ ;  $V_{CC} - V_{EE} = 2.0\text{ V}$ ,  $4.5\text{ V}$ ,  $6.0\text{ V}$  and  $9.0\text{ V}$ .

Symbol	Parameter	Conditions	25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	
$R_{ON(rail)}$	ON resistance (rail)	$V_{is} = V_{EE}$ <a href="#">[2]</a>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 100\text{ }\mu\text{A}$	160	-	-	-	-	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	80	160	-	200	-	240	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	70	140	-	175	-	210	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	60	120	-	150	-	180	$\Omega$
		$V_{is} = V_{CC}$ <a href="#">[2]</a>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 100\text{ }\mu\text{A}$	170	-	-	-	-	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	90	180	-	225	-	270	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	80	160	-	200	-	240	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$ ; $I_{SW} = 1000\text{ }\mu\text{A}$	65	135	-	170	-	205	$\Omega$
$\Delta R_{ON}$	ON resistance mismatch between channels	$V_{is} = V_{CC}$ to $V_{EE}$ <a href="#">[2]</a>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	-	-	-	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	16	-	-	-	-	-	$\Omega$
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	9	-	-	-	-	-	$\Omega$
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	6	-	-	-	-	-	$\Omega$

[1] Typical values are measured at  $T_{amb} = 25\text{ }^\circ\text{C}$ .

[2] When supply voltages ( $V_{CC} - V_{EE}$ ) near  $2.0\text{ V}$  the analog switch ON resistance becomes extremely non-linear. When using a supply of  $2\text{ V}$ , it is recommended to use these devices only for transmitting digital signals.

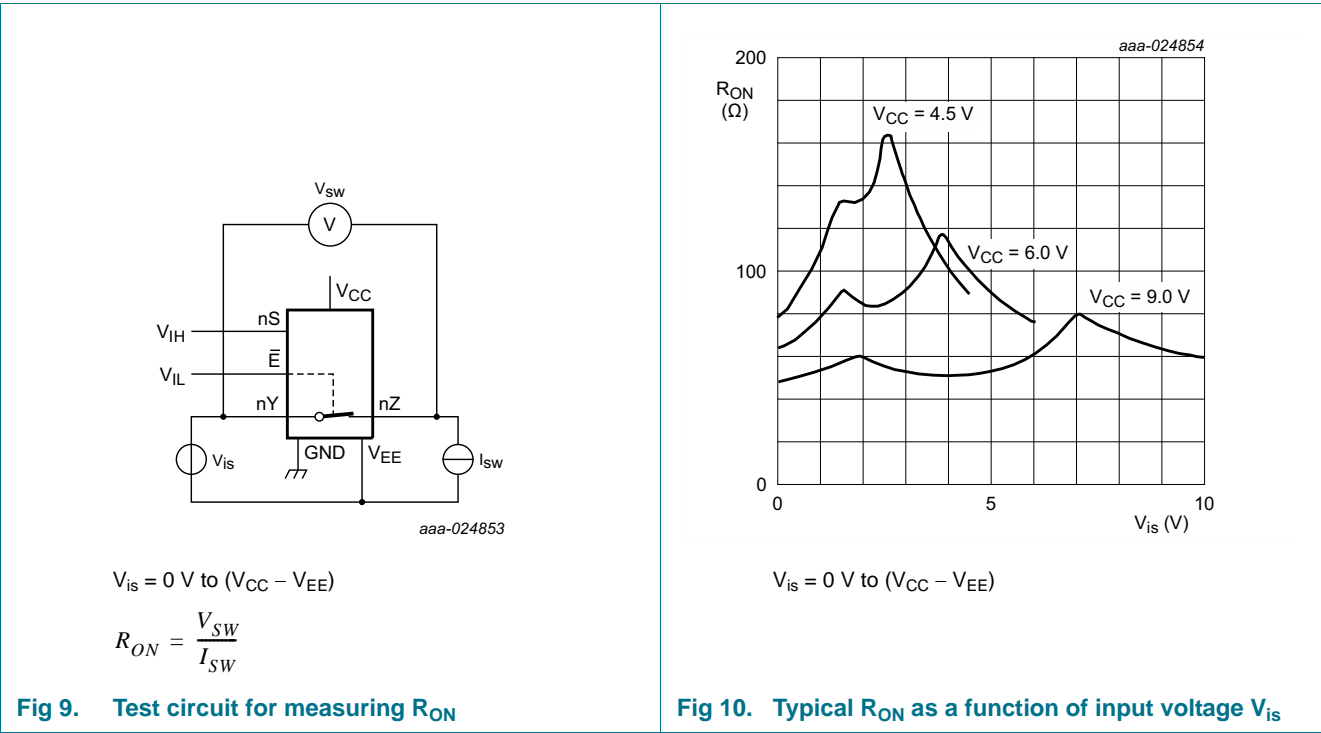


Table 7. Static characteristics 74HC4316

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
		V <sub>CC</sub> = 9.0 V	6.3	4.3	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
		V <sub>CC</sub> = 9.0 V	-	4.3	2.7	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND				
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	±0.1	μA
		V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V	-	-	±0.2	μA
I <sub>S(OFF)</sub>	OFF-state leakage current	V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;  V <sub>SW</sub>   = V <sub>CC</sub> - V <sub>EE</sub> ; see Figure 11	-	-	±0.1	μA
I <sub>S(ON)</sub>	ON-state leakage current	V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;  V <sub>SW</sub>   = V <sub>CC</sub> - V <sub>EE</sub> ; see Figure 12	-	-	±0.1	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>				
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	8.0	μA
		V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V	-	-	16.0	μA



**Table 7. Static characteristics 74HC4316 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

$V_{IS}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{OS}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
C <sub>I</sub>	input capacitance		-	3.5	-	pF
C <sub>SW</sub>	switch capacitance		-	5	-	pF
T <sub>amb</sub> = −40 °C to +85 °C						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
		V <sub>CC</sub> = 9.0 V	6.3	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
		V <sub>CC</sub> = 9.0 V	-	-	2.7	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND				
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	±1.0	μA
		V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V	-	-	±2.0	μA
I <sub>S(OFF)</sub>	OFF-state leakage current	V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;  V <sub>SW</sub>   = V <sub>CC</sub> − V <sub>EE</sub> ; see <a href="#">Figure 11</a>	-	-	±1.0	μA
I <sub>S(ON)</sub>	ON-state leakage current	V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;  V <sub>SW</sub>   = V <sub>CC</sub> − V <sub>EE</sub> ; see <a href="#">Figure 12</a>	-	-	±1.0	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>				
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	80.0	μA
		V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V	-	-	160.0	μA
T <sub>amb</sub> = −40 °C to +125 °C						
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
		V <sub>CC</sub> = 9.0 V	6.3	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
		V <sub>CC</sub> = 9.0 V	-	-	2.7	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND				
		V <sub>CC</sub> = 6.0 V; V <sub>EE</sub> = 0 V	-	-	±1.0	μA
		V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V	-	-	±2.0	μA
I <sub>S(OFF)</sub>	OFF-state leakage current	V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;  V <sub>SW</sub>   = V <sub>CC</sub> − V <sub>EE</sub> ; see <a href="#">Figure 11</a>	-	-	±1.0	μA
I <sub>S(ON)</sub>	ON-state leakage current	V <sub>CC</sub> = 10.0 V; V <sub>EE</sub> = 0 V; V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ;  V <sub>SW</sub>   = V <sub>CC</sub> − V <sub>EE</sub> ; see <a href="#">Figure 12</a>	-	-	±1.0	μA

**Table 7. Static characteristics 74HC4316 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
$I_{CC}$	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or $V_{CC}$ ; $V_{os} = V_{CC}$ or $V_{EE}$				
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	160	$\mu\text{A}$
		$V_{CC} = 10.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	320	$\mu\text{A}$

[1] Typical values are measured at  $T_{amb} = 25\text{ }^\circ\text{C}$ .

**Table 8. Static characteristics 74HCT4316**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
<b><math>T_{amb} = 25\text{ }^\circ\text{C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$	2.0	1.6	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$	-	1.2	0.8	V
$I_I$	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	$\pm 0.1$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 11</a>	-	-	$\pm 0.1$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $V_I = V_{IH}$ or $V_{IL}$ ; $ V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 12</a>	-	-	$\pm 0.1$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = V_{CC}$ or GND; $V_{is} = V_{EE}$ or $V_{CC}$ ; $V_{os} = V_{CC}$ or $V_{EE}$				
		$V_{CC} = 5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	-	8.0	$\mu\text{A}$
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = -5.0\text{ V}$	-	-	16.0	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	nS and $\bar{E}$ ; per input pin; $V_I = V_{CC} - 2.1\text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5\text{ V}$ to $5.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	50	180	$\mu\text{A}$
$C_I$	input capacitance		-	3.5	-	pF
$C_{SW}$	switch capacitance		-	5	-	pF

**Table 8.** Static characteristics 74HCT4316 ...continued

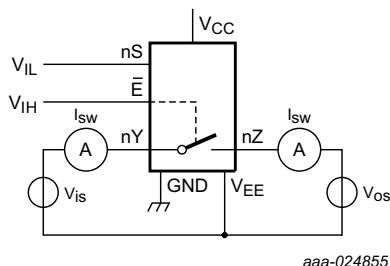
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

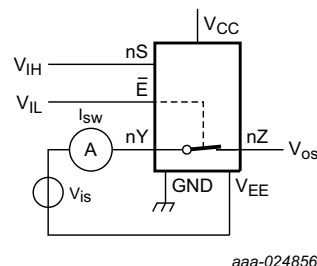
Symbol	Parameter	Conditions	Min	Typ <sup>[1]</sup>	Max	Unit
<b><math>T_{amb} = -40\text{ °C to }+85\text{ °C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	-	0.8	V
$I_I$	input leakage current	$V_I = V_{CC}\text{ or GND}; V_{CC} = 5.5\text{ V}; V_{EE} = 0\text{ V}$	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10\text{ V}; V_{EE} = 0\text{ V}; V_I = V_{IH}\text{ or }V_{IL};  V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 11</a>	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10\text{ V}; V_{EE} = 0\text{ V}; V_I = V_{IH}\text{ or }V_{IL};  V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 12</a>	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = V_{CC}\text{ or GND}; V_{is} = V_{EE}\text{ or }V_{CC}; V_{os} = V_{CC}\text{ or }V_{EE}$				
		$V_{CC} = 5.5\text{ V}; V_{EE} = 0\text{ V}$	-	-	80	$\mu\text{A}$
		$V_{CC} = 5.0\text{ V}; V_{EE} = -5.0\text{ V}$	-	-	160	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	nS and $\bar{E}$ ; per input pin; $V_I = V_{CC} - 2.1\text{ V}$ ; other inputs at $V_{CC}\text{ or GND}$ ; $V_{CC} = 4.5\text{ V to }5.5\text{ V}; V_{EE} = 0\text{ V}$	-	-	225	$\mu\text{A}$
<b><math>T_{amb} = -40\text{ °C to }+125\text{ °C}</math></b>						
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	2.0	-	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	-	-	0.8	V
$I_I$	input leakage current	$V_I = V_{CC}\text{ or GND}; V_{CC} = 5.5\text{ V}; V_{EE} = 0\text{ V}$	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	$V_{CC} = 10\text{ V}; V_{EE} = 0\text{ V}; V_I = V_{IH}\text{ or }V_{IL};  V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 11</a>	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	$V_{CC} = 10\text{ V}; V_{EE} = 0\text{ V}; V_I = V_{IH}\text{ or }V_{IL};  V_{SW}  = V_{CC} - V_{EE}$ ; see <a href="#">Figure 12</a>	-	-	$\pm 1.0$	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = V_{CC}\text{ or GND}; V_{is} = V_{EE}\text{ or }V_{CC}; V_{os} = V_{CC}\text{ or }V_{EE}$				
		$V_{CC} = 5.5\text{ V}; V_{EE} = 0\text{ V}$	-	-	160	$\mu\text{A}$
		$V_{CC} = 5.0\text{ V}; V_{EE} = -5.0\text{ V}$	-	-	320	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	nS and $\bar{E}$ ; per input pin; $V_I = V_{CC} - 2.1\text{ V}$ ; other inputs at $V_{CC}\text{ or GND}$ ; $V_{CC} = 4.5\text{ V to }5.5\text{ V}; V_{EE} = 0\text{ V}$	-	-	245	$\mu\text{A}$

[1] Typical values are measured at  $T_{amb} = 25\text{ °C}$ .



$V_{is} = V_{CC}$  and  $V_{os} = V_{EE}$   
 $V_{is} = V_{EE}$  and  $V_{os} = V_{CC}$

**Fig 11. Test circuit for measuring OFF-state leakage current**



$V_{is} = V_{CC}$  and  $V_{os} = \text{open}$   
 $V_{is} = V_{EE}$  and  $V_{os} = \text{open}$

**Fig 12. Test circuit for measuring ON-state leakage current**

## 11. Dynamic characteristics

**Table 9. Dynamic characteristics 74HC4316**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless specified otherwise; for test circuit see [Figure 15](#).

$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	
$t_{pd}$	propagation delay	nY to nZ or nZ to nY; $R_L = \infty\ \Omega$ ; see <a href="#">Figure 13</a> <sup>[2]</sup>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	17	60	-	75	-	90	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	6	12	-	15	-	18	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	5	10	-	13	-	15	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	4	8	-	10	-	12	ns
$t_{off}$	turn-off time	$\bar{E}$ to nY or nZ; see <a href="#">Figure 14</a> <sup>[4]</sup>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	63	220	-	275	-	330	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	23	44	-	55	-	66	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	20	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	18	37	-	47	-	56	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	21	39	-	49	-	59	ns
		nS to nY or nZ; see <a href="#">Figure 14</a> <sup>[4]</sup>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	55	175	-	220	-	265	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	20	35	-	44	-	53	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	16	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	16	30	-	37	-	45	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	18	36	-	45	-	54	ns

**Table 9.** Dynamic characteristics 74HC4316 ...continued

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless specified otherwise; for test circuit see [Figure 15](#).

$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	
$t_{on}$	turn-on time	E to nY or nZ; see <a href="#">Figure 14</a> <sup>[3]</sup>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	61	205	-	255	-	310	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	22	41	-	51	-	62	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	19	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	18	35	-	43	-	53	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	19	37	-	47	-	56	ns
		nS to nY or nZ; see <a href="#">Figure 14</a> <sup>[3]</sup>							
		$V_{CC} = 2.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	52	175	-	220	-	265	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	19	35	-	44	-	53	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	16	-	-	-	-	-	ns
		$V_{CC} = 6.0\text{ V}$ ; $V_{EE} = 0\text{ V}$	15	30	-	37	-	45	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	17	34	-	43	-	51	ns
$C_{PD}$	power dissipation capacitance	per switch; $V_I = GND$ to $V_{CC}$ <sup>[5]</sup>	13	-	-	-	-	-	pF

[1] Typical values are measured at  $T_{amb} = 25\text{ °C}$ .

[2]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[3]  $t_{on}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

[4]  $t_{off}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$\sum\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  = sum of outputs;

$C_L$  = output load capacitance in pF;

$C_{sw}$  = switch capacitance in pF;

$V_{CC}$  = supply voltage in V.

**Table 10. Dynamic characteristics 74HCT4316**

$GND = 0\text{ V}$ ;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless specified otherwise; for test circuit see [Figure 15](#).

$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

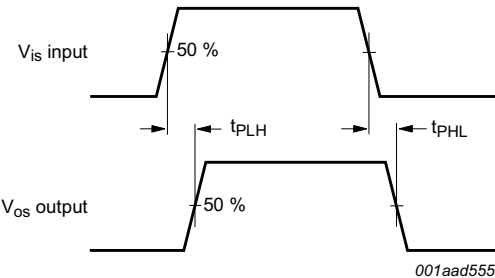
Symbol	Parameter	Conditions	25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	
$t_{pd}$	propagation delay	nY to nZ or nZ to nY; $R_L = \infty\ \Omega$ ; <a href="#">[2]</a> see <a href="#">Figure 13</a>							
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	6	12	-	15	-	18	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	4	8	-	10	-	12	ns
$t_{pZH}$	OFF-state to HIGH propagation delay	$\bar{E}$ to nY or nZ; see <a href="#">Figure 14</a>							
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	22	44	-	55	-	66	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	19	-	-	-	-	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	21	42	-	53	-	63	ns
		nS to nY or nZ; see <a href="#">Figure 14</a>							
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	20	40	-	53	-	60	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	17	-	-	-	-	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	17	34	-	43	-	51	ns
$t_{pZL}$	OFF-state to LOW propagation delay	$\bar{E}$ to nY or nZ; see <a href="#">Figure 14</a>							
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	28	56	-	70	-	84	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	24	-	-	-	-	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	21	42	-	53	-	63	ns
		nS to nY or nZ; see <a href="#">Figure 14</a>							
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	25	50	-	63	-	75	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	21	-	-	-	-	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	17	34	-	43	-	51	ns
$t_{off}$	turn-off time	$\bar{E}$ to nY or nZ; see <a href="#">Figure 14</a> <a href="#">[3]</a>							
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	25	50	-	63	-	75	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	21	-	-	-	-	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	23	46	-	58	-	69	ns
		nS to nY or nZ; see <a href="#">Figure 14</a>							
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	22	44	-	55	-	66	ns
		$V_{CC} = 5.0\text{ V}$ ; $V_{EE} = 0\text{ V}$ ; $C_L = 15\text{ pF}$	19	-	-	-	-	-	ns
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	20	40	-	50	-	60	ns

**Table 10. Dynamic characteristics 74HCT4316 ...continued**  
*GND = 0 V;  $t_r = t_f = 6\text{ ns}$ ;  $C_L = 50\text{ pF}$  unless specified otherwise; for test circuit see [Figure 15](#).  
 $V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.  
 $V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.*

Symbol	Parameter	Conditions	25 °C		–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	
$C_{PD}$	power dissipation capacitance	per switch; $V_I = \text{GND to } (V_{CC} - 1.5\text{ V})$ <sup>[4]</sup>	14	-	-	-	-	-	pF

- [1] Typical values are measured at  $T_{amb} = 25\text{ °C}$ .
- [2]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .
- [3]  $t_{off}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  where:  
 $f_i$  = input frequency in MHz;  
 $f_o$  = output frequency in MHz;  
 $\sum\{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$  = sum of outputs;  
 $C_L$  = output load capacitance in pF;  
 $C_{sw}$  = switch capacitance in pF;  
 $V_{CC}$  = supply voltage in V.

## 12. Waveforms



**Fig 13. Input ( $V_{is}$ ) to output ( $V_{os}$ ) propagation delays**

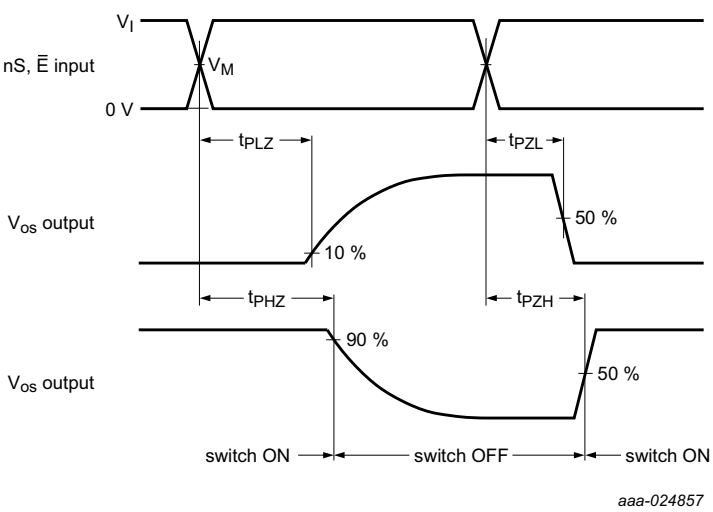
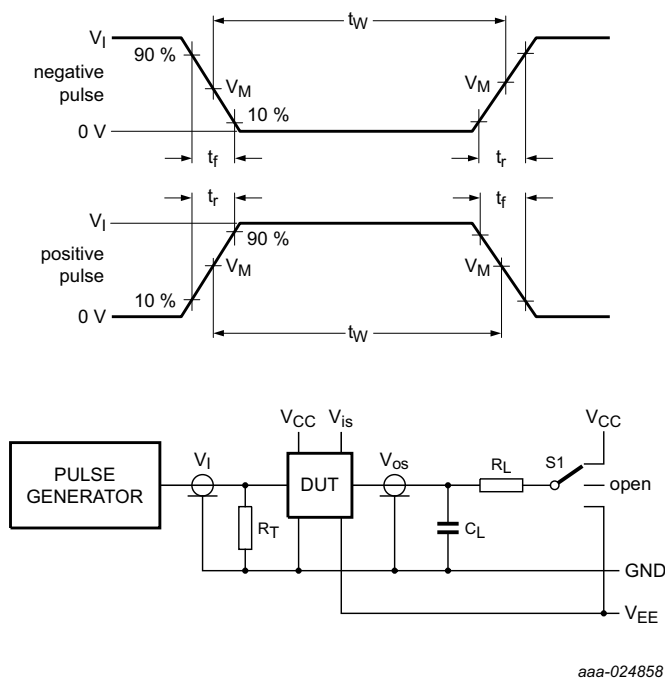


Fig 14. Turn-on and turn-off times

Table 11. Measurement points

Type	V <sub>I</sub>	V <sub>M</sub>
74HC4316	V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT4316	3.0 V	1.3 V





Test data is given in [Table 12](#).

Definitions test circuit:

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_L$  = Load resistance.

S1 = Test selection switch.

Fig 15. Test circuit for measuring switching times

Table 12. Test data

Test	Input					Output		S1 position
	$\overline{E}$	nS	Switch nY (nZ)	$t_r, t_f$		Switch nZ (nY)		
	$V_I$		$V_{is}$	at $f_{max}$	other <sup>[1]</sup>	$C_L$	$R_L$	
$t_{PHL}, t_{PLH}$	[2]		GND to $V_{CC}$	< 2 ns	6 ns	50 pF	-	open
$t_{PHZ}, t_{PZH}$	[2]		$V_{CC}$	< 2 ns	6 ns	50 pF, 15 pF	1 kΩ	$V_{EE}$
$t_{PLZ}, t_{PZL}$	[2]		$V_{EE}$	< 2 ns	6 ns	50 pF, 15 pF	1 kΩ	$V_{CC}$

[1]  $t_r = t_f = 6$  ns; when measuring  $f_{max}$ , there is no constraint to  $t_r$  and  $t_f$  with 50 % duty factor.

[2]  $V_I$  values:

- a) For 74HC4316:  $V_I = V_{CC}$
- b) For 74HCT4316:  $V_I = 3$  V

### 13. Additional dynamic characteristics

**Table 13. Additional dynamic characteristics**

Recommended conditions and typical values;  $GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $C_L = 50\text{ pF}$ .

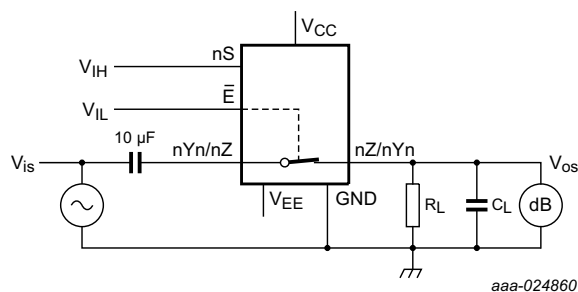
$V_{is}$  is the input voltage at a nY or nZ terminal, whichever is assigned as an input.

$V_{os}$  is the output voltage at a nY or nZ terminal, whichever is assigned as an output.

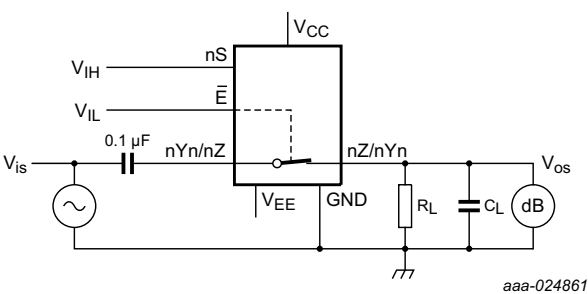
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	$f_i = 1\text{ kHz}$ ; $R_L = 10\text{ k}\Omega$ ; see <a href="#">Figure 16</a>				
		$V_{is} = 4.0\text{ V (p-p)}$ ; $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	-	0.80	-	%
		$V_{is} = 8.0\text{ V (p-p)}$ ; $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	0.40	-	%
		$f_i = 10\text{ kHz}$ ; $R_L = 10\text{ k}\Omega$ ; see <a href="#">Figure 16</a>				
		$V_{is} = 4.0\text{ V (p-p)}$ ; $V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	-	2.40	-	%
		$V_{is} = 8.0\text{ V (p-p)}$ ; $V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	1.20	-	%
$f_{(-3\text{dB})}$	–3 dB frequency response	$R_L = 50\text{ }\Omega$ ; $C_L = 10\text{ pF}$ ; see <a href="#">Figure 17</a> <a href="#">[1]</a>				
		$V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	-	150	-	MHz
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	160	-	MHz
$\alpha_{iso}$	isolation (OFF-state)	$R_L = 600\text{ }\Omega$ ; $f_i = 1\text{ MHz}$ ; see <a href="#">Figure 18</a> <a href="#">[2]</a>				
		$V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	-	–50	-	dB
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	–50	-	dB
$V_{ct}$	crosstalk voltage	peak-to-peak value; between control and any switch; $R_L = 600\text{ }\Omega$ ; $f_i = 1\text{ MHz}$ ; $\bar{E}$ or nS square wave between $V_{CC}$ and GND; $t_r = t_f = 6\text{ ns}$ ; see <a href="#">Figure 19</a>				
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = 0\text{ V}$	-	110	-	mV
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	220	-	mV
Xtalk	crosstalk	between switches; $R_L = 600\text{ }\Omega$ ; $f_i = 1\text{ MHz}$ ; see <a href="#">Figure 20</a> <a href="#">[2]</a>				
		$V_{CC} = 2.25\text{ V}$ ; $V_{EE} = -2.25\text{ V}$	-	–60	-	dB
		$V_{CC} = 4.5\text{ V}$ ; $V_{EE} = -4.5\text{ V}$	-	–60	-	dB

[1] Adjust input voltage  $V_{is}$  to 0 dBm level at  $V_{os}$  for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ).

[2] Adjust input voltage  $V_{is}$  to 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ).

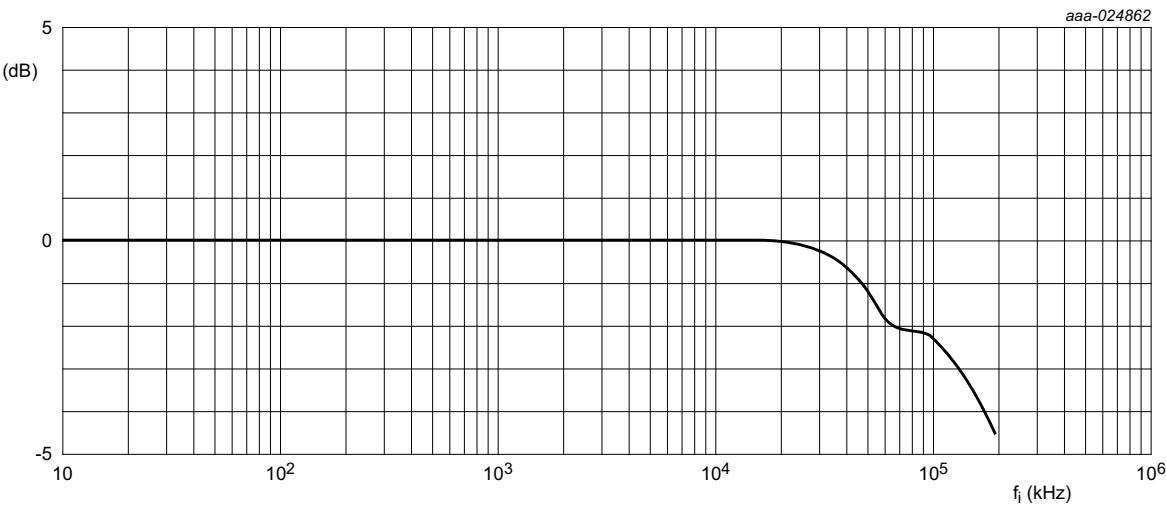


**Fig 16. Test circuit for measuring total harmonic distortion**



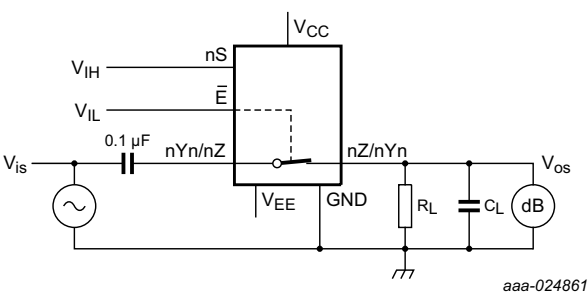
$V_{CC} = 4.5\text{ V}$ ;  $GND = 0\text{ V}$ ;  $V_{EE} = -4.5\text{ V}$ ;  $R_L = 50\text{ }\Omega$ ;  $R_S = 1\text{ k}\Omega$ .

a. Test circuit



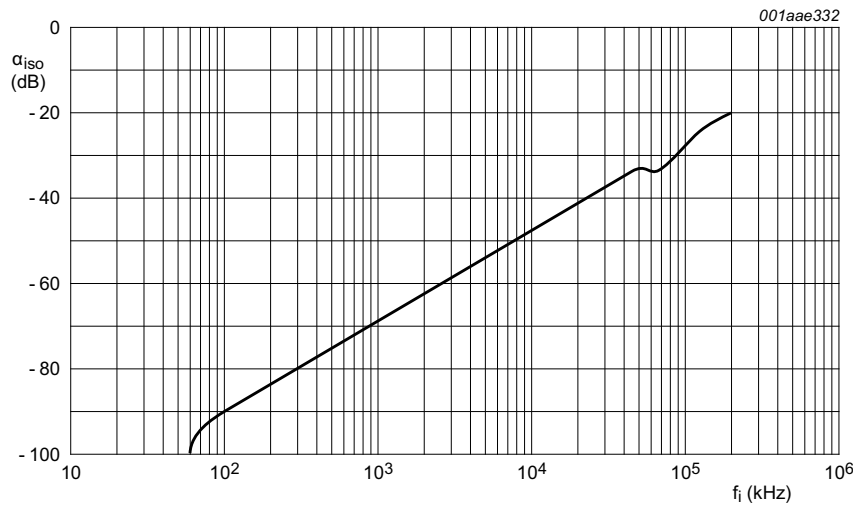
b. Typical -3 dB frequency response

Fig 17. -3 dB frequency response



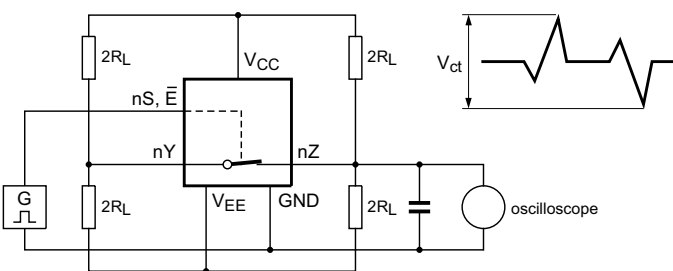
$V_{CC} = 4.5\text{ V}$ ;  $GND = 0\text{ V}$ ;  $V_{EE} = -4.5\text{ V}$ ;  $R_L = 600\ \Omega$ ;  $R_S = 1\text{ k}\Omega$ .

a. Test circuit



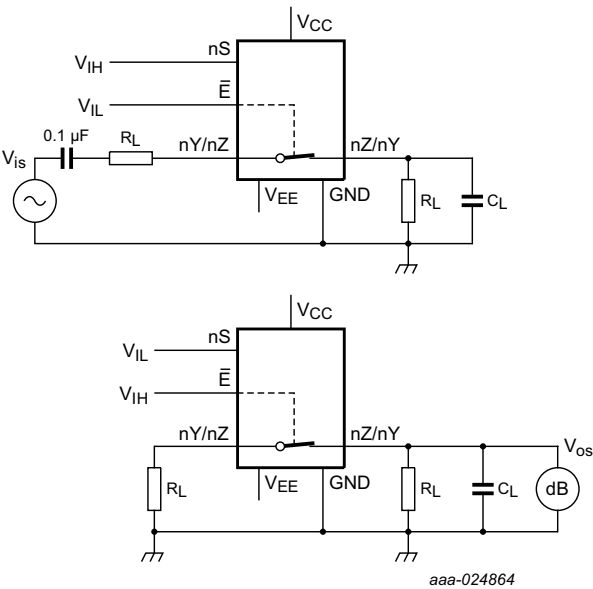
b. Isolation (OFF-state) as a function of frequency

Fig 18. Isolation (OFF-state) as a function of frequency



aaa-024863

Fig 19. Test circuit for measuring crosstalk voltage (between the digital input and the switch)



aaa-024864

Fig 20. Test circuit for measuring crosstalk (between the switches)

14. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

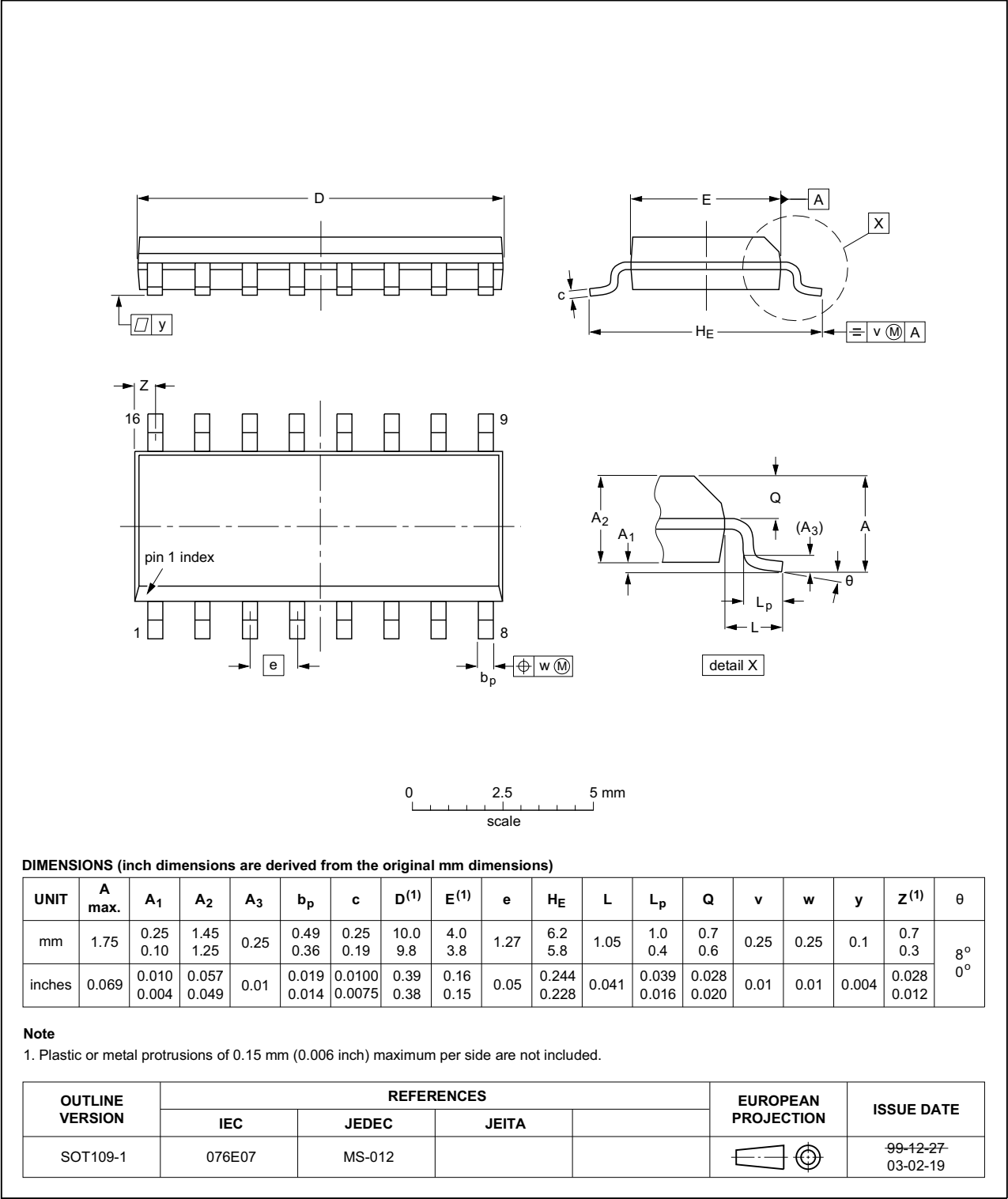


Fig 21. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

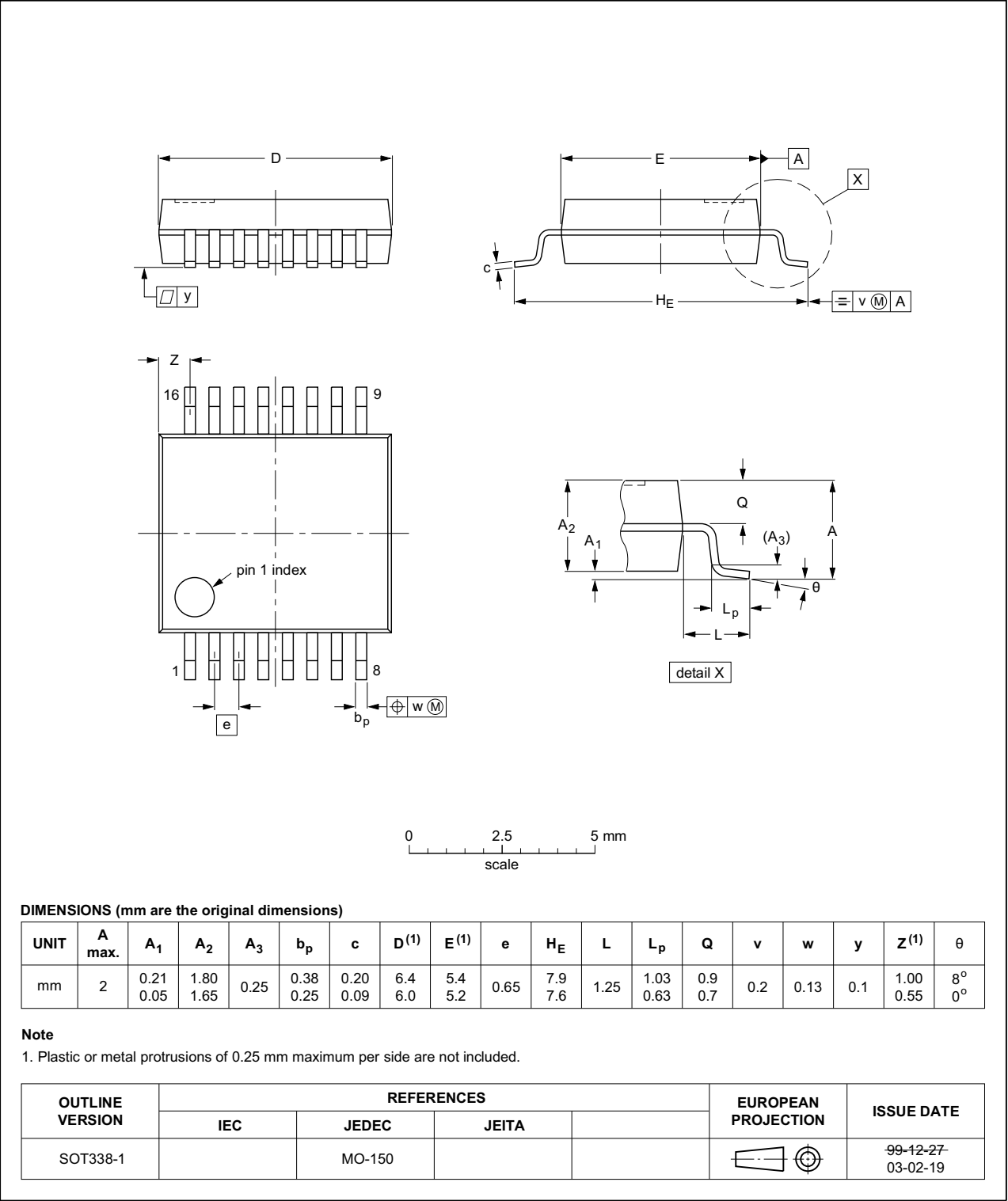


Fig 22. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

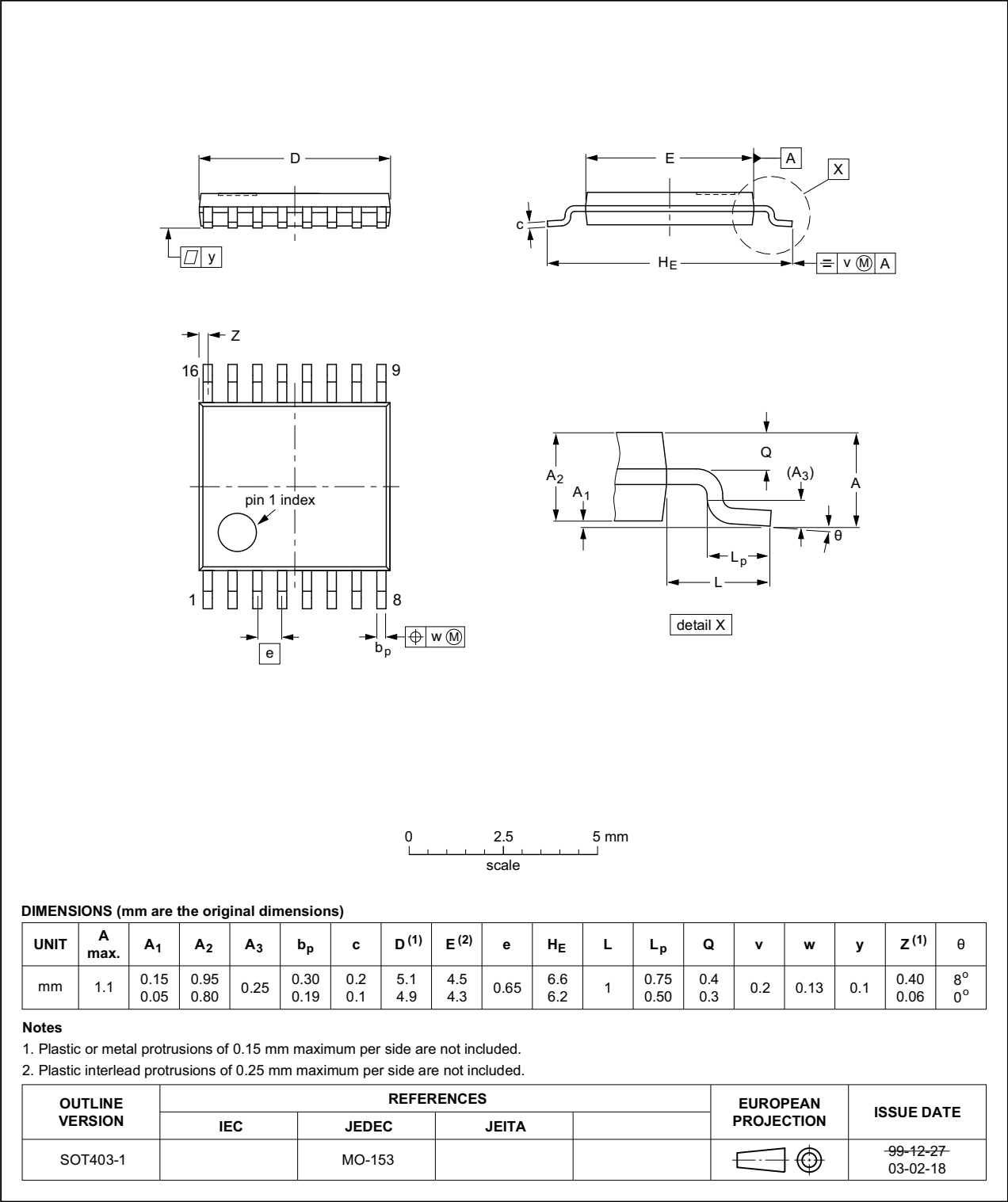


Fig 23. Package outline SOT403-1 (TSSOP16)



## 15. Abbreviations

Table 14. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

## 16. Revision history

Table 15. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4316 v.3	20170102	Product data sheet	-	74HC_HCT4316_CNV v.2
Modifications:	<ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• Type numbers 74HC4316N and 74HCT4316N removed.</li></ul>			
74HC_HCT4316_CNV v.2	19930901	Product specification	-	-

## 17. Legal information

### 17.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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